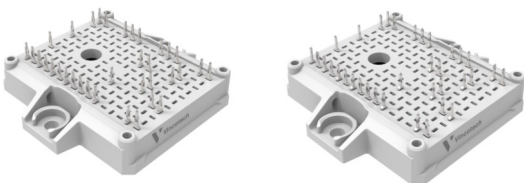
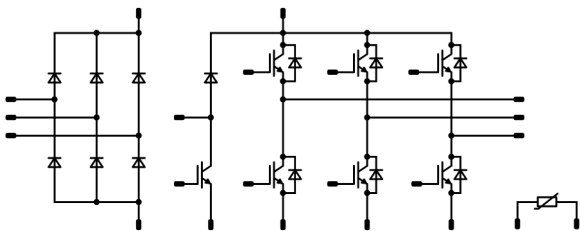




Vincotech

# 10-EY12PMA015M7-L186A78T 10-E212PMA015M7-L186A78Z

datasheet

| flowPIM E2                                                                                                                                                                                                                                                            |  | 1200 V / 15 A                                                                                                                                        |  |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| <b>Features</b> <ul style="list-style-type: none"> <li>IGBT M7 with low <math>V_{CEsat}</math> and improved EMC behavior</li> <li>Standard industrial housing</li> <li>Optimized <math>R_{th(j-s)}</math> with Phase Change Material</li> <li>Built-in NTC</li> </ul> |  | <b>flow E2 12 mm housing</b>  <p>Press-fit pin      Solder pin</p> |  |
| <b>Target applications</b> <ul style="list-style-type: none"> <li>Industrial Drives</li> </ul>                                                                                                                                                                        |  | <b>Schematic</b>                                                  |  |
| <b>Types</b> <ul style="list-style-type: none"> <li>10-EY12PMA015M7-L186A78T</li> <li>10-E212PMA015M7-L186A78Z</li> </ul>                                                                                                                                             |  |                                                                                                                                                      |  |

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

| Parameter                         | Symbol     | Condition                             | Value    | Unit |
|-----------------------------------|------------|---------------------------------------|----------|------|
| <b>Inverter Switch</b>            |            |                                       |          |      |
| Collector-emitter voltage         | $V_{CES}$  |                                       | 1200     | V    |
| Collector current                 | $I_C$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 21       | A    |
| Repetitive peak collector current | $I_{CRM}$  | $t_p$ limited by $T_{jmax}$           | 30       | A    |
| Total power dissipation           | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 64       | W    |
| Gate-emitter voltage              | $V_{GES}$  |                                       | $\pm 20$ | V    |
| Maximum junction temperature      | $T_{jmax}$ |                                       | 175      | °C   |



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**10-EY12PMA015M7-L186A78T**  
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## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------|--------|-----------|-------|------|
|-----------|--------|-----------|-------|------|

### Inverter Diode

|                                     |            |                                       |      |    |
|-------------------------------------|------------|---------------------------------------|------|----|
| Peak repetitive reverse voltage     | $V_{RRM}$  |                                       | 1200 | V  |
| Continuous (direct) forward current | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 21   | A  |
| Repetitive peak forward current     | $I_{FRM}$  | $T_j$ limited by $T_{jmax}$           | 30   | A  |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 51   | W  |
| Maximum junction temperature        | $T_{jmax}$ |                                       | 175  | °C |

### Brake Switch

|                                   |            |                                       |      |    |
|-----------------------------------|------------|---------------------------------------|------|----|
| Collector-emitter voltage         | $V_{CES}$  |                                       | 1200 | V  |
| Collector current                 | $I_C$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 21   | A  |
| Repetitive peak collector current | $I_{CRM}$  | $t_p$ limited by $T_{jmax}$           | 30   | A  |
| Total power dissipation           | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 64   | W  |
| Gate-emitter voltage              | $V_{GES}$  |                                       | ±20  | V  |
| Maximum junction temperature      | $T_{jmax}$ |                                       | 175  | °C |

### Brake Diode

|                                     |            |                                       |      |    |
|-------------------------------------|------------|---------------------------------------|------|----|
| Peak repetitive reverse voltage     | $V_{RRM}$  |                                       | 1200 | V  |
| Continuous (direct) forward current | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 14   | A  |
| Repetitive peak forward current     | $I_{FRM}$  | $T_j$ limited by $T_{jmax}$           | 20   | A  |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 43   | W  |
| Maximum junction temperature        | $T_{jmax}$ |                                       | 175  | °C |

### Rectifier Diode

|                                        |            |                                                                           |      |                  |
|----------------------------------------|------------|---------------------------------------------------------------------------|------|------------------|
| Peak repetitive reverse voltage        | $V_{RRM}$  |                                                                           | 1600 | V                |
| Continuous (direct) forward current    | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$                                     | 47   | A                |
| Surge (non-repetitive) forward current | $I_{FSM}$  | 50 Hz Single Half Sine Wave<br>$t_p = 10\text{ ms}$ $T_j = 150\text{ °C}$ | 270  | A                |
| Surge current capability               | $I^2t$     |                                                                           | 370  | A <sup>2</sup> s |
| Total power dissipation                | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$                                     | 58   | W                |
| Maximum junction temperature           | $T_{jmax}$ |                                                                           | 150  | °C               |



Vincotech

**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
datasheet

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------|--------|-----------|-------|------|
|-----------|--------|-----------|-------|------|

### Module Properties

#### Thermal Properties

|                                                   |                  |  |                                 |    |
|---------------------------------------------------|------------------|--|---------------------------------|----|
| Storage temperature                               | $T_{\text{stg}}$ |  | -40...+125                      | °C |
| Operation temperature under switching condition** | $T_{\text{jop}}$ |  | -40...( $T_{\text{jmax}}$ - 25) | °C |

#### Isolation Properties

|                            |                   |                                     |             |    |
|----------------------------|-------------------|-------------------------------------|-------------|----|
| Isolation voltage          | $V_{\text{isol}}$ | DC Test Voltage* $t_p = 2\text{ s}$ | 6000        | V  |
|                            |                   | AC Voltage $t_p = 1\text{ min}$     | 2500        | V  |
| Creepage distance          |                   |                                     | min. 12,7   | mm |
| Clearance                  |                   | Press-fit pin / Solder pin          | 8,83 / 8,85 | mm |
| Comparative Tracking Index | CTI               |                                     | ≥ 600       |    |

\*100 % tested in production

\*\* $T_{\text{jmax}} > T_j > T_{\text{jop}}$  is allowed only for short time overload of selected semiconductor components under switching conditions.



Vincotech

**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Characteristic Values

| Parameter | Symbol | Conditions |                              |                                           |                                     |            | Value |     |     | Unit |
|-----------|--------|------------|------------------------------|-------------------------------------------|-------------------------------------|------------|-------|-----|-----|------|
|           |        |            | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Inverter Switch

#### Static

|                                      |              |  |    |      |        |                  |     |                      |      |    |
|--------------------------------------|--------------|--|----|------|--------|------------------|-----|----------------------|------|----|
| Gate-emitter threshold voltage       | $V_{GE(th)}$ |  |    | 10   | 0,0015 | 25               | 5,4 | 6,0                  | 6,6  | V  |
| Collector-emitter saturation voltage | $V_{CEsat}$  |  | 15 |      | 15     | 25<br>125<br>150 |     | 1,70<br>1,95<br>2,01 | 2,15 | V  |
| Collector-emitter cut-off current    | $I_{CES}$    |  | 0  | 1200 |        | 25               |     |                      | 60   | μA |
| Gate-emitter leakage current         | $I_{GES}$    |  | 20 | 0    |        | 25               |     |                      | 500  | nA |
| Internal gate resistance             | $r_g$        |  |    |      |        |                  |     | none                 |      | Ω  |
| Input capacitance                    | $C_{ies}$    |  | 0  | 10   | 25     |                  |     | 2900                 |      | pF |
| Output capacitance                   | $C_{oes}$    |  |    |      |        |                  |     | 120                  |      |    |
| Reverse transfer capacitance         | $C_{res}$    |  |    |      |        |                  |     | 34                   |      |    |
| Gate charge                          | $Q_g$        |  | 15 | 600  | 15     | 25               |     | 110                  |      | nC |

#### Thermal

|                                     |               |                                               |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|-----------------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$<br>(PSX) |  |  |  |  |  | 1,49 |  | K/W |
|-------------------------------------|---------------|-----------------------------------------------|--|--|--|--|--|------|--|-----|

#### Dynamic

|                              |              |                                                 |          |     |    |                  |  |                       |  |     |
|------------------------------|--------------|-------------------------------------------------|----------|-----|----|------------------|--|-----------------------|--|-----|
| Turn-on delay time           | $t_{d(on)}$  | $R_{gon} = 32 \Omega$<br>$R_{goff} = 32 \Omega$ | $\pm 15$ | 600 | 15 | 25<br>125<br>150 |  | 196<br>191<br>190     |  | ns  |
| Rise time                    | $t_r$        |                                                 |          |     |    | 25<br>125<br>150 |  | 60<br>63<br>64        |  |     |
| Turn-off delay time          | $t_{d(off)}$ |                                                 |          |     |    | 25<br>125<br>150 |  | 181<br>206<br>211     |  |     |
| Fall time                    | $t_f$        |                                                 |          |     |    | 25<br>125<br>150 |  | 95<br>113<br>114      |  |     |
| Turn-on energy (per pulse)*  | $E_{on}$     |                                                 |          |     |    | 25<br>125<br>150 |  | 1,69<br>2,11<br>2,21  |  | mWs |
| Turn-off energy (per pulse)* | $E_{off}$    |                                                 |          |     |    | 25<br>125<br>150 |  | 0,987<br>1,33<br>1,41 |  |     |

\*  $L_s = 10 \text{ nH}$



Vincotech

**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Characteristic Values

| Parameter | Symbol | Conditions |                              |                                           |                                     |            | Value |     |     | Unit |
|-----------|--------|------------|------------------------------|-------------------------------------------|-------------------------------------|------------|-------|-----|-----|------|
|           |        |            | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Inverter Diode

#### Static

|                         |       |  |  |      |    |                  |  |                      |     |    |
|-------------------------|-------|--|--|------|----|------------------|--|----------------------|-----|----|
| Forward voltage         | $V_F$ |  |  |      | 15 | 25<br>125<br>150 |  | 1,63<br>1,74<br>1,73 | 2,1 | V  |
| Reverse leakage current | $I_R$ |  |  | 1200 |    | 25               |  |                      | 30  | µA |

#### Thermal

|                                     |               |                                               |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|-----------------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$<br>(PSX) |  |  |  |  |  | 1,88 |  | K/W |
|-------------------------------------|---------------|-----------------------------------------------|--|--|--|--|--|------|--|-----|

#### Dynamic

|                                       |                      |                                                                                                                   |          |     |    |                  |  |                        |  |      |
|---------------------------------------|----------------------|-------------------------------------------------------------------------------------------------------------------|----------|-----|----|------------------|--|------------------------|--|------|
| Peak recovery current                 | $I_{RRM}$            | $di/dt = 181 \text{ A/}\mu\text{s}$<br>$di/dt = 205 \text{ A/}\mu\text{s}$<br>$di/dt = 175 \text{ A/}\mu\text{s}$ | $\pm 15$ | 600 | 15 | 25<br>125<br>150 |  | 9<br>11<br>11          |  | A    |
| Reverse recovery time                 | $t_{rr}$             |                                                                                                                   |          |     |    | 25<br>125<br>150 |  | 286<br>422<br>471      |  | ns   |
| Recovered charge                      | $Q_r$                |                                                                                                                   |          |     |    | 25<br>125<br>150 |  | 1,50<br>2,46<br>2,68   |  | µC   |
| Reverse recovered energy              | $E_{rec}$            |                                                                                                                   |          |     |    | 25<br>125<br>150 |  | 0,497<br>0,913<br>1,00 |  | mWs  |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ |                                                                                                                   |          |     |    | 25<br>125<br>150 |  | 77<br>49<br>44         |  | A/µs |



Vincotech

**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Characteristic Values

| Parameter | Symbol | Conditions |                              |                                           |                                     |            | Value |     |     | Unit |
|-----------|--------|------------|------------------------------|-------------------------------------------|-------------------------------------|------------|-------|-----|-----|------|
|           |        |            | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Brake Switch

#### Static

|                                      |              |   |    |      |        |                  |     |                      |      |    |
|--------------------------------------|--------------|---|----|------|--------|------------------|-----|----------------------|------|----|
| Gate-emitter threshold voltage       | $V_{GE(th)}$ |   |    | 10   | 0,0015 | 25               | 5,4 | 6,0                  | 6,6  | V  |
| Collector-emitter saturation voltage | $V_{CEsat}$  |   | 15 |      | 15     | 25<br>125<br>150 |     | 1,70<br>1,95<br>2,01 | 2,15 | V  |
| Collector-emitter cut-off current    | $I_{CES}$    |   | 0  | 1200 |        | 25               |     |                      | 60   | µA |
| Gate-emitter leakage current         | $I_{GES}$    |   | 20 | 0    |        | 25               |     |                      | 500  | nA |
| Internal gate resistance             | $r_g$        |   |    |      |        |                  |     | none                 |      | Ω  |
| Input capacitance                    | $C_{ies}$    | 0 | 10 |      | 25     |                  |     | 2900                 |      | pF |
| Output capacitance                   | $C_{oes}$    |   |    |      |        |                  |     | 120                  |      |    |
| Reverse transfer capacitance         | $C_{res}$    |   |    |      |        |                  |     | 34                   |      |    |
| Gate charge                          | $Q_g$        |   | 15 | 600  | 15     | 25               |     | 110                  |      | nC |

#### Thermal

|                                     |               |                                               |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|-----------------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$<br>(PSX) |  |  |  |  |  | 1,49 |  | K/W |
|-------------------------------------|---------------|-----------------------------------------------|--|--|--|--|--|------|--|-----|

#### Dynamic

|                             |              |                                                 |        |     |    |                  |  |                      |  |     |
|-----------------------------|--------------|-------------------------------------------------|--------|-----|----|------------------|--|----------------------|--|-----|
| Turn-on delay time          | $t_{d(on)}$  | $R_{gon} = 32 \Omega$<br>$R_{goff} = 32 \Omega$ | 0 / 15 | 600 | 15 | 25<br>125<br>150 |  | 300<br>262<br>253    |  | ns  |
| Rise time                   | $t_r$        |                                                 |        |     |    | 25<br>125<br>150 |  | 194<br>205<br>209    |  |     |
| Turn-off delay time         | $t_{d(off)}$ |                                                 |        |     |    | 25<br>125<br>150 |  | 388<br>428<br>438    |  |     |
| Fall time                   | $t_f$        |                                                 |        |     |    | 25<br>125<br>150 |  | 67<br>87<br>89       |  |     |
| Turn-on energy (per pulse)  | $E_{on}$     |                                                 |        |     |    | 25<br>125<br>150 |  | 2,50<br>3,01<br>3,19 |  | mWs |
| Turn-off energy (per pulse) | $E_{off}$    |                                                 |        |     |    | 25<br>125<br>150 |  | 1,12<br>1,44<br>1,54 |  |     |



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**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Characteristic Values

| Parameter | Symbol | Conditions |                              |                                           |                                     |            | Value |     |     | Unit |
|-----------|--------|------------|------------------------------|-------------------------------------------|-------------------------------------|------------|-------|-----|-----|------|
|           |        |            | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Brake Diode

#### Static

|                         |       |  |  |      |    |                  |  |                      |     |    |
|-------------------------|-------|--|--|------|----|------------------|--|----------------------|-----|----|
| Forward voltage         | $V_F$ |  |  |      | 10 | 25<br>125<br>150 |  | 1,61<br>1,69<br>1,69 | 2,1 | V  |
| Reverse leakage current | $I_R$ |  |  | 1200 |    | 25               |  |                      | 25  | μA |

#### Thermal

|                                     |               |                                       |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4$ W/mK<br>(PSX) |  |  |  |  |  | 2,19 |  | K/W |
|-------------------------------------|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|

#### Dynamic

|                                       |                      |                                                             |        |     |    |                  |  |                         |  |      |
|---------------------------------------|----------------------|-------------------------------------------------------------|--------|-----|----|------------------|--|-------------------------|--|------|
| Peak recovery current                 | $I_{RRM}$            | $di/dt = 74$ A/μs<br>$di/dt = 65$ A/μs<br>$di/dt = 62$ A/μs | 0 / 15 | 600 | 15 | 25<br>125<br>150 |  | 6<br>7<br>7             |  | A    |
| Reverse recovery time                 | $t_{rr}$             |                                                             |        |     |    | 25<br>125<br>150 |  | 317<br>473<br>542       |  | ns   |
| Recovered charge                      | $Q_r$                |                                                             |        |     |    | 25<br>125<br>150 |  | 1,11<br>1,78<br>2,04    |  | μC   |
| Reverse recovered energy              | $E_{rec}$            |                                                             |        |     |    | 25<br>125<br>150 |  | 0,368<br>0,644<br>0,753 |  | mWs  |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ |                                                             |        |     |    | 25<br>125<br>150 |  | 40<br>28<br>24          |  | A/μs |

### Rectifier Diode

#### Static

|                         |       |  |  |      |    |           |  |              |    |    |
|-------------------------|-------|--|--|------|----|-----------|--|--------------|----|----|
| Forward voltage         | $V_F$ |  |  |      | 35 | 25<br>125 |  | 1,17<br>1,13 |    | V  |
| Reverse leakage current | $I_R$ |  |  | 1600 |    | 25        |  |              | 50 | μA |

#### Thermal

|                                     |               |                                       |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4$ W/mK<br>(PSX) |  |  |  |  |  | 1,20 |  | K/W |
|-------------------------------------|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|



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**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Characteristic Values

| Parameter | Symbol | Conditions |                              |                                           |                                     |            | Value |     |     | Unit |
|-----------|--------|------------|------------------------------|-------------------------------------------|-------------------------------------|------------|-------|-----|-----|------|
|           |        |            | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Thermistor

|                            |                |                        |  |  |  |     |    |      |    |      |
|----------------------------|----------------|------------------------|--|--|--|-----|----|------|----|------|
| Rated resistance           | $R$            |                        |  |  |  | 25  |    | 5    |    | kΩ   |
| Deviation of $R_{100}$     | $\Delta_{R/R}$ | $R_{100} = 493 \Omega$ |  |  |  | 100 | -5 |      | +5 | %    |
| Power dissipation          | $P$            |                        |  |  |  | 25  |    | 245  |    | mW   |
| Power dissipation constant |                |                        |  |  |  | 25  |    | 1,4  |    | mW/K |
| B-value                    | $B_{(25/50)}$  | Tol. $\pm 2 \%$        |  |  |  | 25  |    | 3375 |    | K    |
| B-value                    | $B_{(25/100)}$ | Tol. $\pm 2 \%$        |  |  |  | 25  |    | 3437 |    | K    |
| Vincotech NTC Reference    |                |                        |  |  |  |     |    |      | K  |      |





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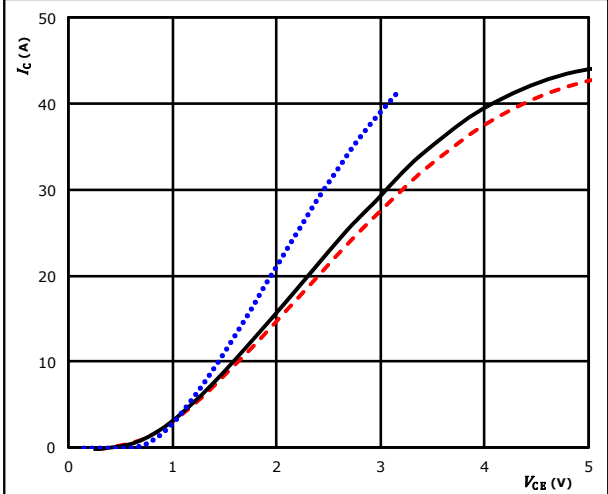
**10-EY12PMA015M7-L186A78T**  
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 datasheet

## Inverter Switch Characteristics

**figure 1.** IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

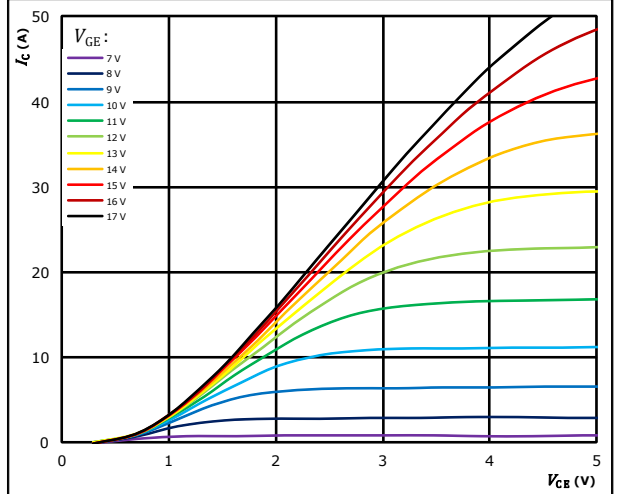


$t_p = 250 \mu s$   $T_j: 25 \text{ } ^\circ C$  (blue dotted line)  
 $V_{GE} = 15 \text{ V}$   $125 \text{ } ^\circ C$  (black solid line)  
 $150 \text{ } ^\circ C$  (red dashed line)

**figure 2.** IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

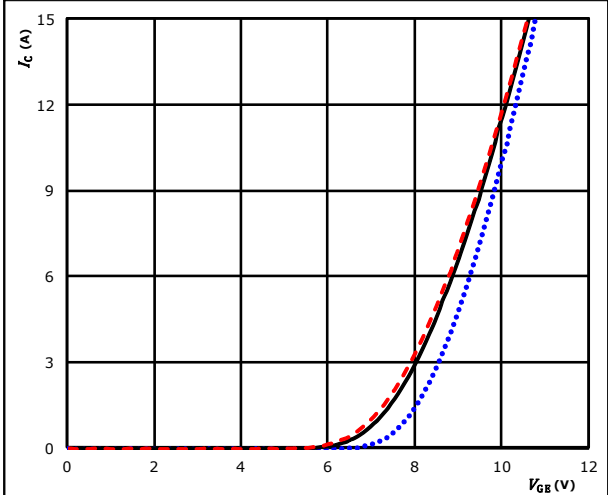


$t_p = 250 \mu s$   $T_j = 150 \text{ } ^\circ C$   
 $V_{GE}$  from 7 V to 17 V in steps of 1 V

**figure 3.** IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

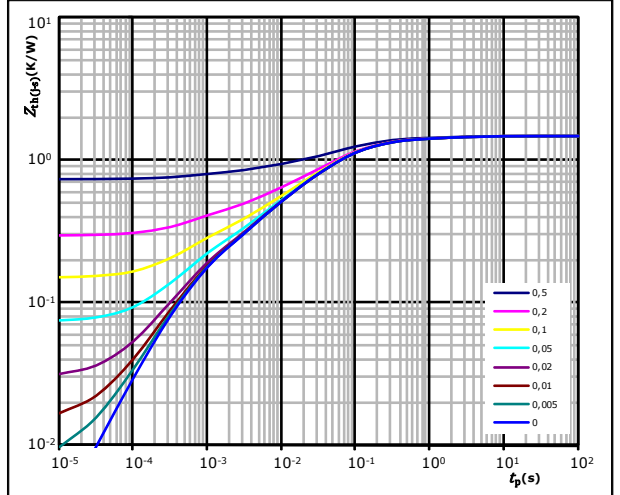


$t_p = 100 \mu s$   $T_j: 25 \text{ } ^\circ C$  (blue dotted line)  
 $V_{CE} = 10 \text{ V}$   $125 \text{ } ^\circ C$  (black solid line)  
 $150 \text{ } ^\circ C$  (red dashed line)

**figure 4.** IGBT

Transient thermal impedance as function of pulse duration

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 1,49 \text{ K/W}$   
 IGBT thermal model values  

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 4,90E-02          | 3,61E+00           |
| 1,10E-01          | 6,54E-01           |
| 4,70E-01          | 1,09E-01           |
| 4,98E-01          | 2,97E-02           |
| 2,21E-01          | 4,73E-03           |
| 1,37E-01          | 5,51E-04           |



Vincotech

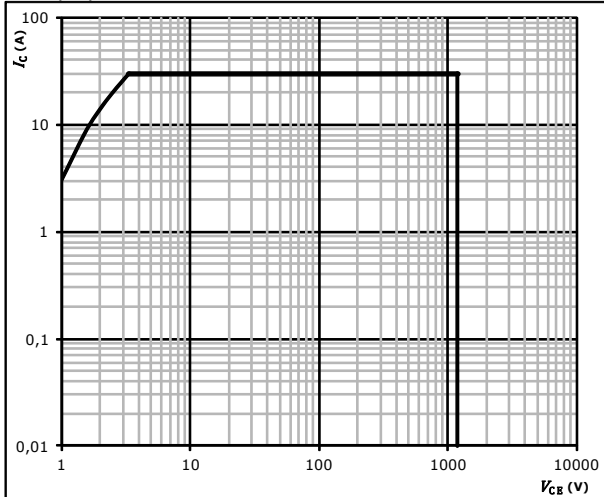
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
datasheet

## Inverter Switch Characteristics

**figure 5.** IGBT

Safe operating area

$I_C = f(V_{CE})$



$D =$  single pulse  
 $T_s =$  80 °C  
 $V_{GE} =$  ±15 V  
 $T_j =$   $T_{jmax}$



Vincotech

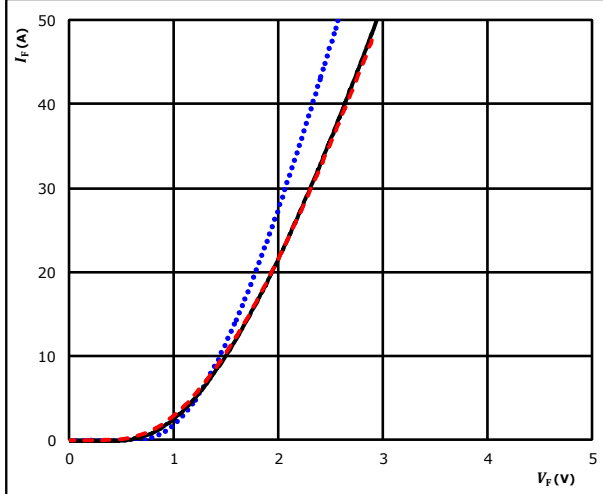
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Inverter Diode Characteristics

**figure 1.** FWD

Typical forward characteristics

$$I_F = f(V_F)$$

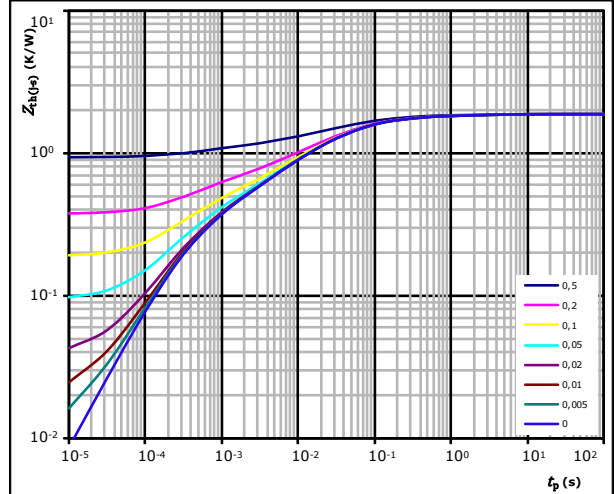


$t_p =$  250  $\mu s$   $T_j$ : 25 °C .....  
 125 °C ———  
 150 °C - - - -

**figure 2.** FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 1,88$  K/W  
 FWD thermal model values

| $R$ (K/W) | $\tau$ (s) |
|-----------|------------|
| 7,31E-02  | 2,45E+00   |
| 1,93E-01  | 2,55E-01   |
| 6,27E-01  | 4,97E-02   |
| 4,83E-01  | 1,15E-02   |
| 2,56E-01  | 2,33E-03   |
| 2,42E-01  | 3,41E-04   |



Vincotech

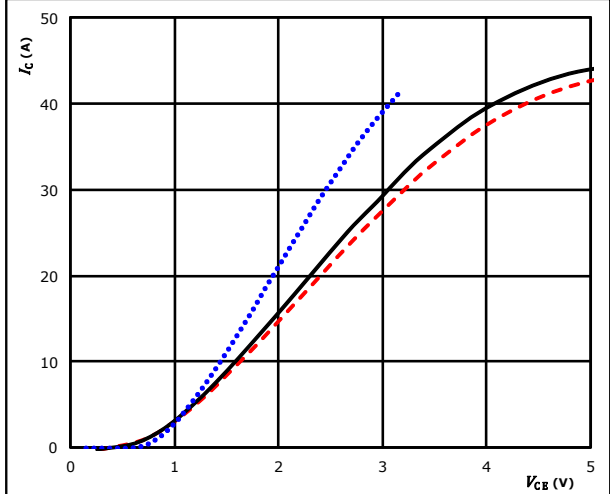
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Brake Switch Characteristics

**figure 1.** IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

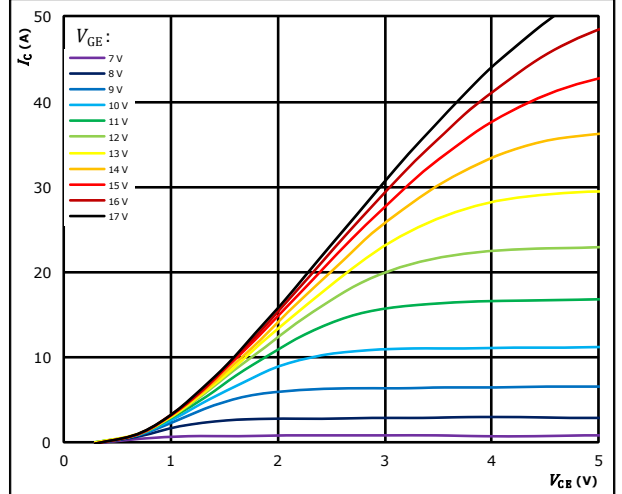


$t_p = 250 \mu s$   
 $V_{GE} = 15 V$   
 $T_j: 25 \text{ } ^\circ C$  (blue dotted)  
 $125 \text{ } ^\circ C$  (black solid)  
 $150 \text{ } ^\circ C$  (red dashed)

**figure 2.** IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

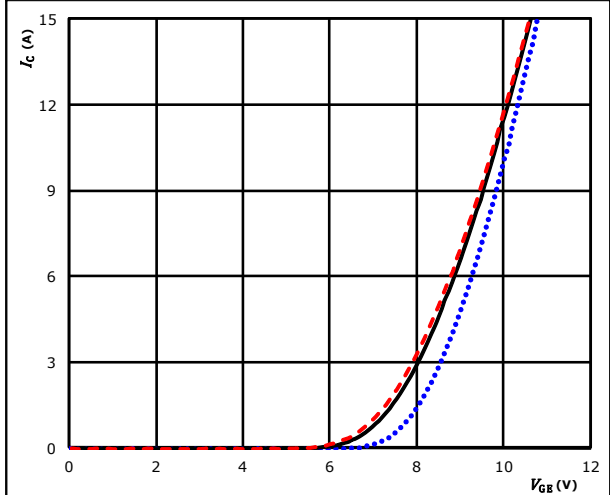


$t_p = 250 \mu s$   
 $T_j = 150 \text{ } ^\circ C$   
 $V_{GE}$  from 7 V to 17 V in steps of 1 V

**figure 3.** IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

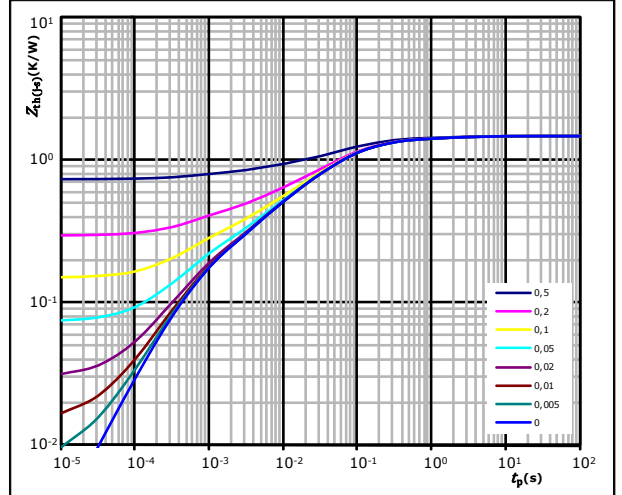


$t_p = 100 \mu s$   
 $V_{CE} = 10 V$   
 $T_j: 25 \text{ } ^\circ C$  (blue dotted)  
 $125 \text{ } ^\circ C$  (black solid)  
 $150 \text{ } ^\circ C$  (red dashed)

**figure 4.** IGBT

Transient thermal impedance as function of pulse duration

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 1,49 \text{ K/W}$   
 IGBT thermal model values

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 4,90E-02          | 3,61E+00           |
| 1,10E-01          | 6,54E-01           |
| 4,70E-01          | 1,09E-01           |
| 4,98E-01          | 2,97E-02           |
| 2,21E-01          | 4,73E-03           |
| 1,37E-01          | 5,51E-04           |



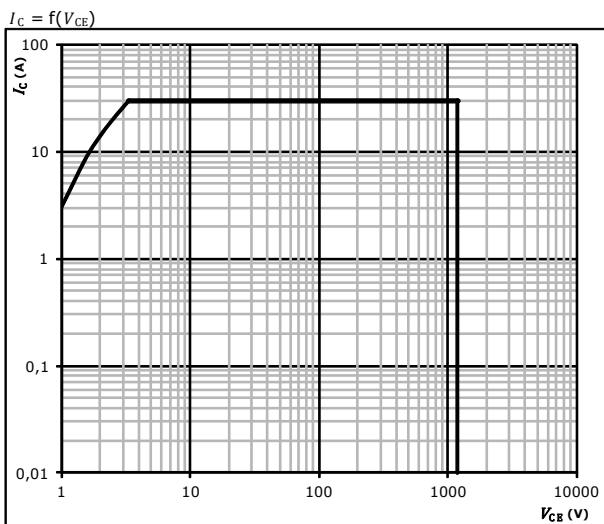
Vincotech

**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
datasheet

## Brake Switch Characteristics

**figure 5.** IGBT

Safe operating area



$D =$  single pulse  
 $T_s =$  80 °C  
 $V_{GE} =$  ±15 V  
 $T_j =$   $T_{jmax}$



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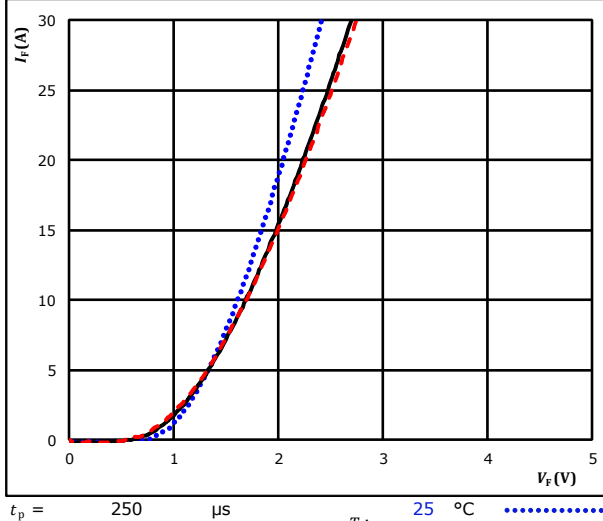
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
datasheet

## Brake Diode Characteristics

**figure 1.** FWD

Typical forward characteristics

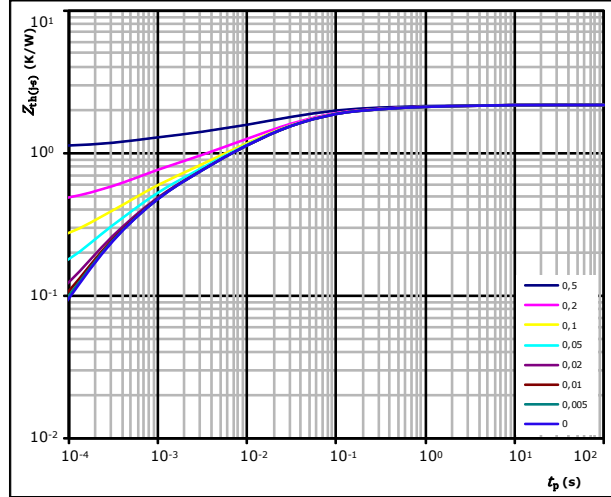
$$I_F = f(V_F)$$



**figure 2.** FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$$D = \frac{t_p}{T}$$

$$R_{th(j-s)} = 2,19 \text{ K/W}$$

FWD thermal model values

| $R$ (K/W) | $\tau$ (s) |
|-----------|------------|
| 8,09E-02  | 3,20E+00   |
| 2,08E-01  | 2,82E-01   |
| 6,85E-01  | 4,41E-02   |
| 5,92E-01  | 1,02E-02   |
| 3,27E-01  | 2,02E-03   |
| 2,95E-01  | 3,64E-04   |



Vincotech

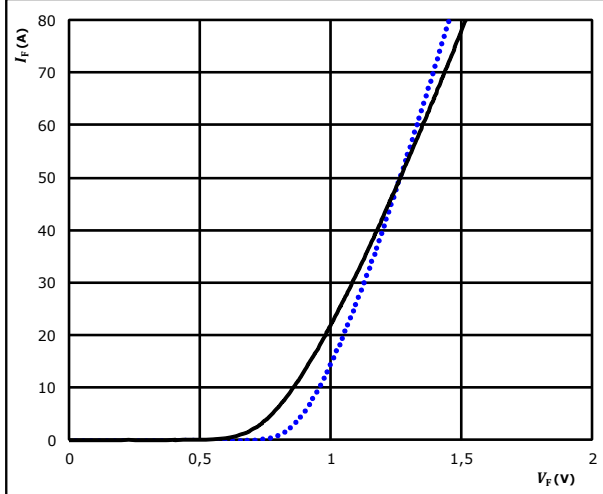
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Rectifier Diode Characteristics

**figure 1.** FWD

Typical forward characteristics

$$I_F = f(V_F)$$

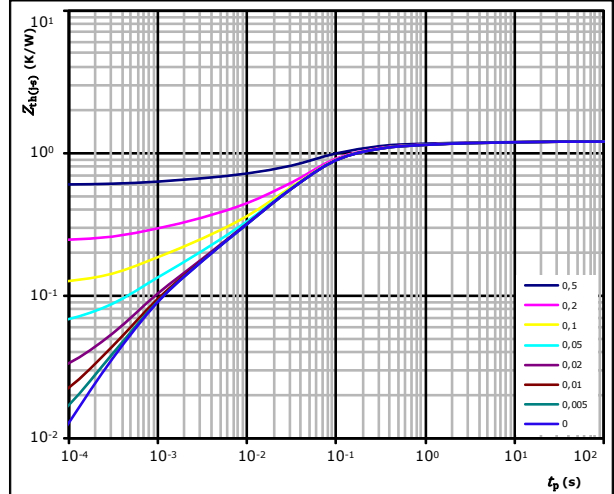


$t_p = 250 \mu s$   
 $T_j: 25 \text{ } ^\circ\text{C}$  (dotted blue line)  
 $125 \text{ } ^\circ\text{C}$  (solid black line)

**figure 2.** FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 1,20 \text{ K/W}$

FWD thermal model values

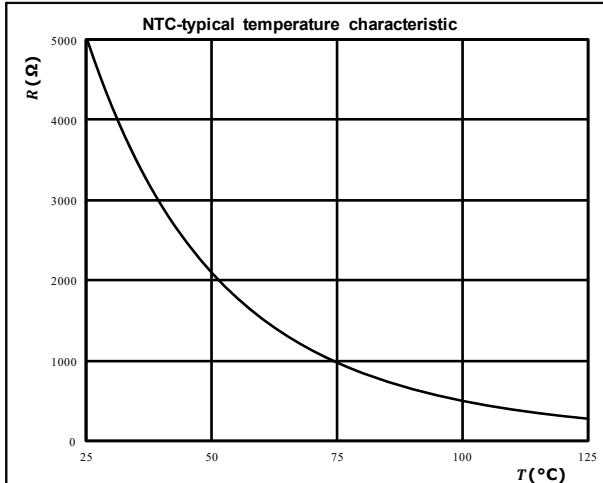
| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 3,54E-02          | 9,31E+00           |
| 8,09E-02          | 9,99E-01           |
| 2,12E-01          | 1,71E-01           |
| 6,76E-01          | 4,85E-02           |
| 1,19E-01          | 5,88E-03           |
| 7,98E-02          | 8,33E-04           |

## Thermistor Characteristics

**figure 1.** Thermistor

Typical NTC characteristic  
 as a function of temperature

$$R = f(T)$$





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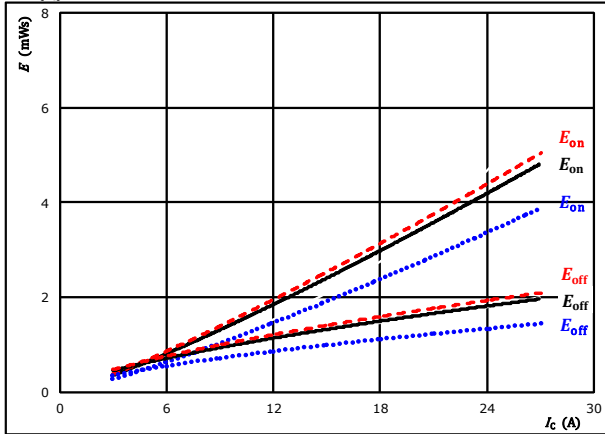
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Inverter Switching Characteristics

**figure 1.** IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 600$  V

$V_{GE} = \pm 15$  V

$R_{gon} = 32$   $\Omega$

$R_{goff} = 32$   $\Omega$

$T_j$ :

25 °C

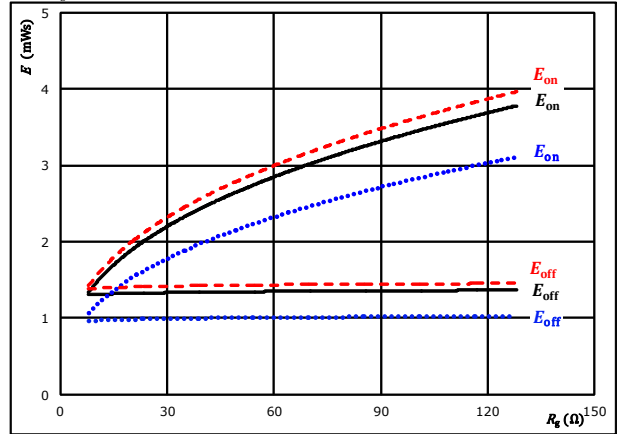
125 °C

150 °C

**figure 2.** IGBT

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 600$  V

$V_{GE} = \pm 15$  V

$I_C = 15$  A

$T_j$ :

25 °C

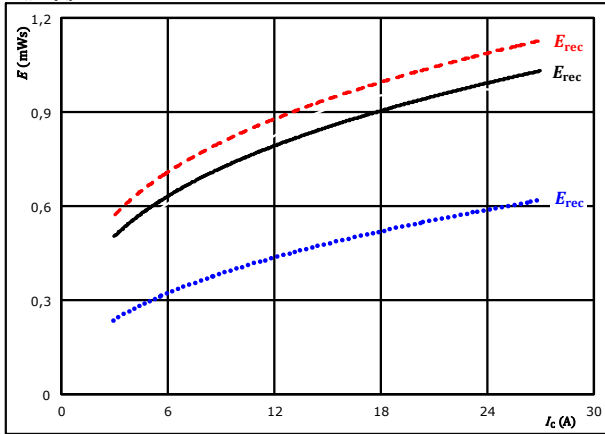
125 °C

150 °C

**figure 3.** FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 600$  V

$V_{GE} = \pm 15$  V

$R_{gon} = 32$   $\Omega$

$T_j$ :

25 °C

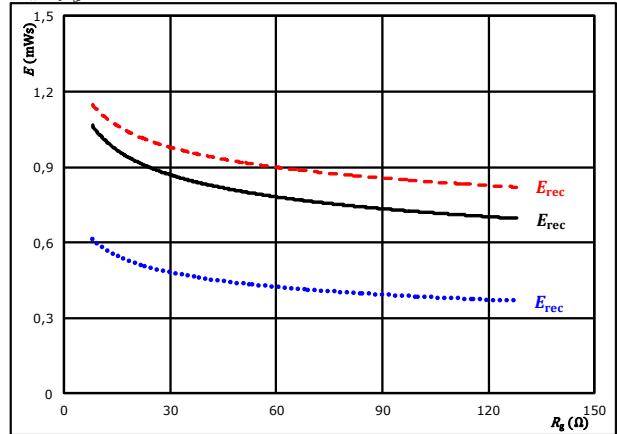
125 °C

150 °C

**figure 4.** FWD

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600$  V

$V_{GE} = \pm 15$  V

$I_C = 15$  A

$T_j$ :

25 °C

125 °C

150 °C





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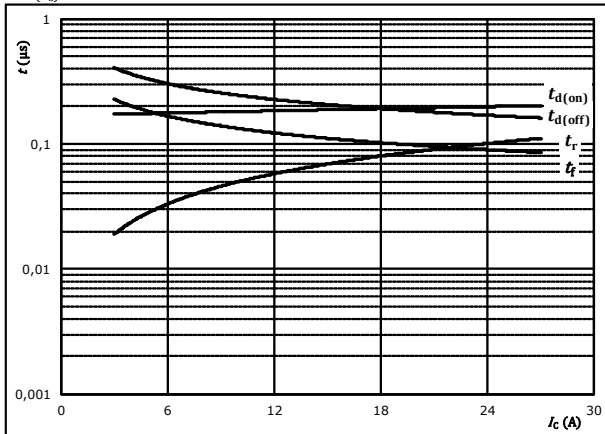
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Inverter Switching Characteristics

**figure 5.** IGBT

Typical switching times as a function of collector current

$$t = f(I_C)$$



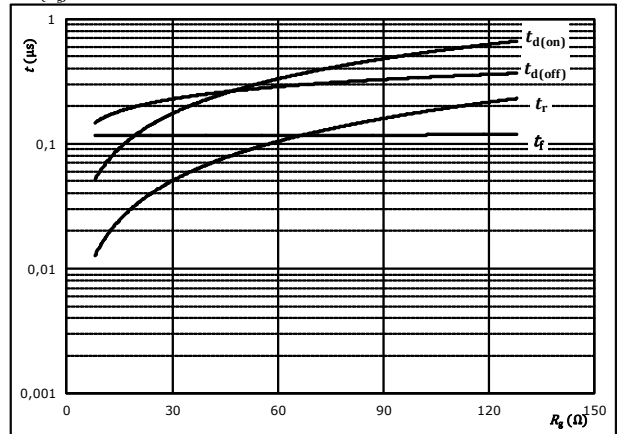
With an inductive load at

|              |     |    |
|--------------|-----|----|
| $T_j =$      | 150 | °C |
| $V_{CE} =$   | 600 | V  |
| $V_{GE} =$   | ±15 | V  |
| $R_{gon} =$  | 32  | Ω  |
| $R_{goff} =$ | 32  | Ω  |

**figure 6.** IGBT

Typical switching times as a function of gate resistor

$$t = f(R_g)$$



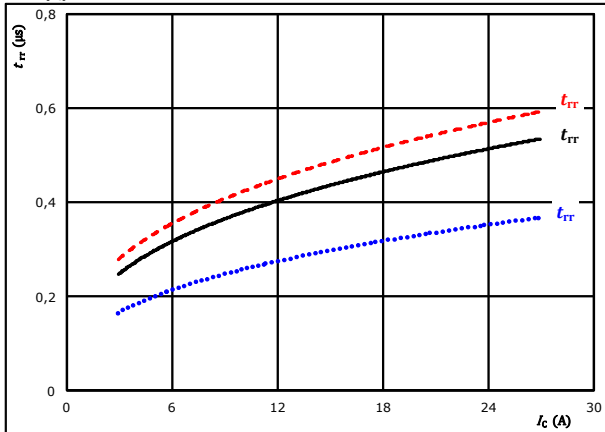
With an inductive load at

|            |     |    |
|------------|-----|----|
| $T_j =$    | 150 | °C |
| $V_{CE} =$ | 600 | V  |
| $V_{GE} =$ | ±15 | V  |
| $I_C =$    | 15  | A  |

**figure 7.** FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_C)$$

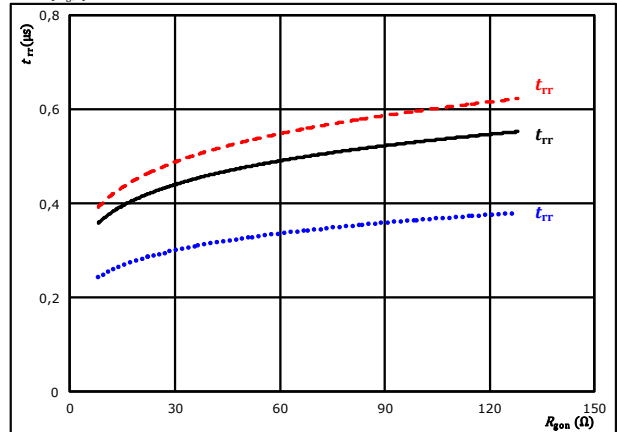


|    |             |     |   |        |        |       |
|----|-------------|-----|---|--------|--------|-------|
| At | $V_{CE} =$  | 600 | V | $T_j:$ | 25 °C  | ..... |
|    | $V_{GE} =$  | ±15 | V |        | 125 °C | ————  |
|    | $R_{gon} =$ | 32  | Ω |        | 150 °C | ----- |

**figure 8.** FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

$$t_{rr} = f(R_{gon})$$



|    |            |     |   |        |        |       |
|----|------------|-----|---|--------|--------|-------|
| At | $V_{CE} =$ | 600 | V | $T_j:$ | 25 °C  | ..... |
|    | $V_{GE} =$ | ±15 | V |        | 125 °C | ————  |
|    | $I_C =$    | 15  | A |        | 150 °C | ----- |



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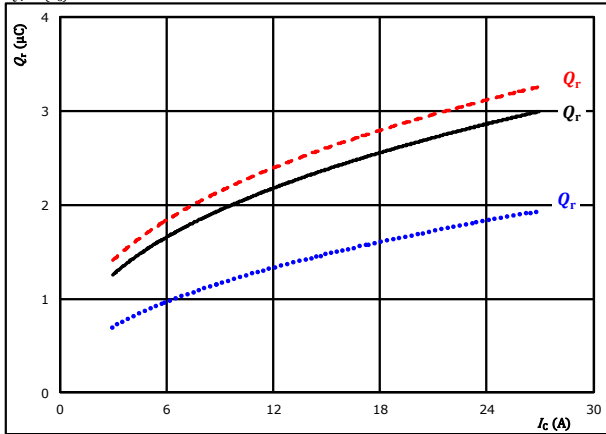
**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Inverter Switching Characteristics

**figure 9.** FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_C)$$

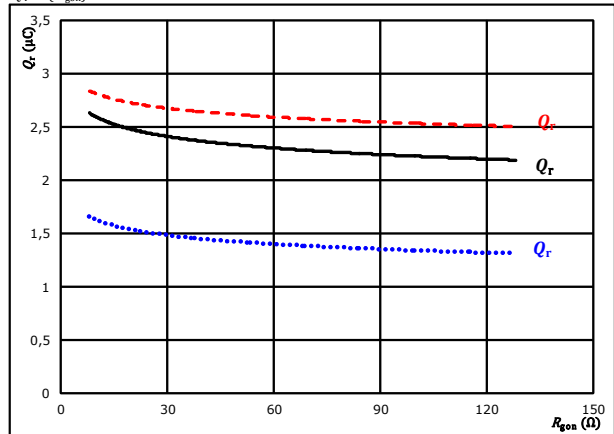


At  $V_{CE} = 600$  V  $T_j = 25$  °C  
 $V_{GE} = \pm 15$  V  $T_j = 125$  °C  
 $R_{gon} = 32$  Ω  $T_j = 150$  °C

**figure 10.** FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$

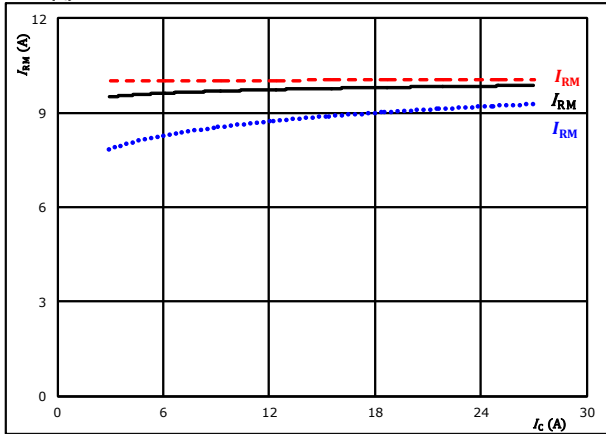


At  $V_{CE} = 600$  V  $T_j = 25$  °C  
 $V_{GE} = \pm 15$  V  $T_j = 125$  °C  
 $I_C = 15$  A  $T_j = 150$  °C

**figure 11.** FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_C)$$

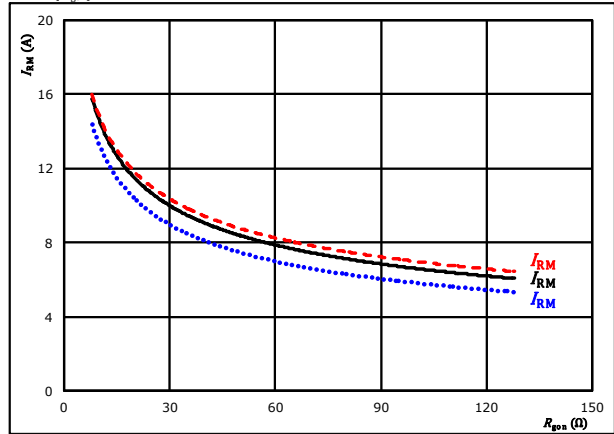


At  $V_{CE} = 600$  V  $T_j = 25$  °C  
 $V_{GE} = \pm 15$  V  $T_j = 125$  °C  
 $R_{gon} = 32$  Ω  $T_j = 150$  °C

**figure 12.** FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



At  $V_{CE} = 600$  V  $T_j = 25$  °C  
 $V_{GE} = \pm 15$  V  $T_j = 125$  °C  
 $I_C = 15$  A  $T_j = 150$  °C



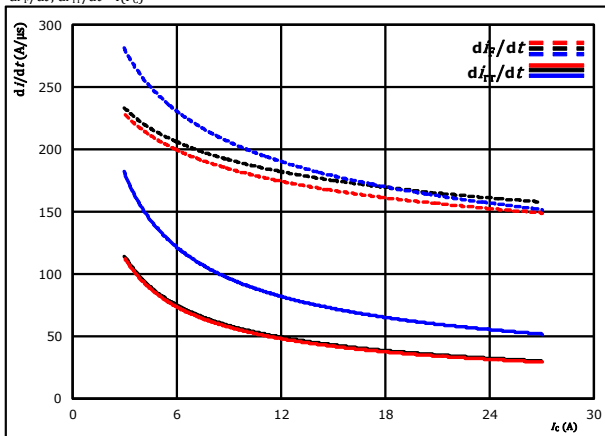
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**10-E212PMA015M7-L186A78Z**  
 datasheet

## Inverter Switching Characteristics

**figure 13.** FWD

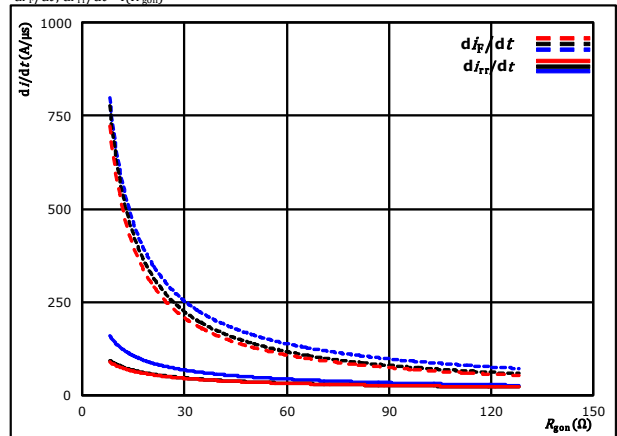
Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_{rr}/dt = f(I_C)$



At  $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 32$   $\Omega$   
 $T_j: 25$  °C  
 125 °C  
 150 °C

**figure 14.** FWD

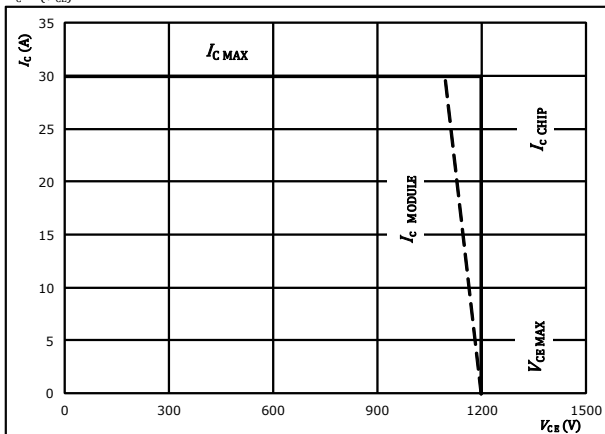
Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor  
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



At  $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_C = 15$  A  
 $T_j: 25$  °C  
 125 °C  
 150 °C

**figure 15.** IGBT

Reverse bias safe operating area  
 $I_C = f(V_{CE})$



At  $T_j = 175$  °C  
 $R_{gon} = 32$   $\Omega$   
 $R_{goff} = 32$   $\Omega$



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 datasheet

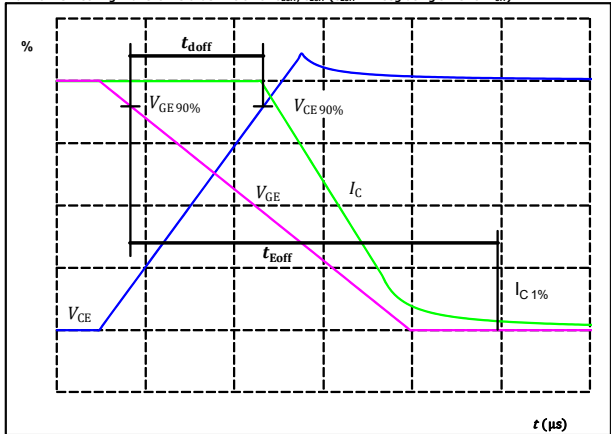
## Inverter Switching Definitions

### General conditions

|            |   |             |
|------------|---|-------------|
| $T_j$      | = | 125 °C      |
| $R_{gon}$  | = | 32 $\Omega$ |
| $R_{goff}$ | = | 32 $\Omega$ |

**figure 1.** IGBT

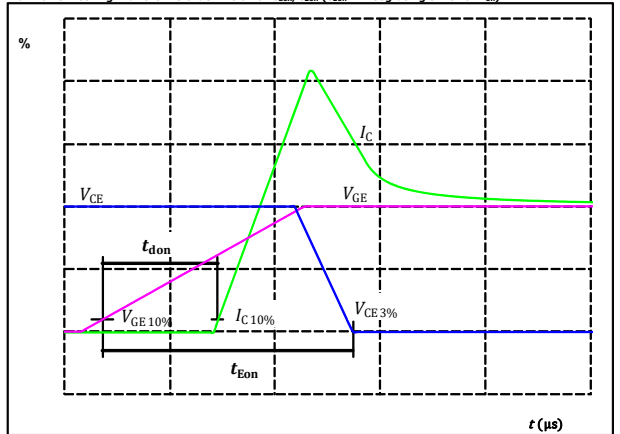
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



|                   |     |    |
|-------------------|-----|----|
| $V_{GE}(0\%) =$   | -15 | V  |
| $V_{GE}(100\%) =$ | 15  | V  |
| $V_C(100\%) =$    | 600 | V  |
| $I_C(100\%) =$    | 15  | A  |
| $t_{doff} =$      | 206 | ns |

**figure 2.** IGBT

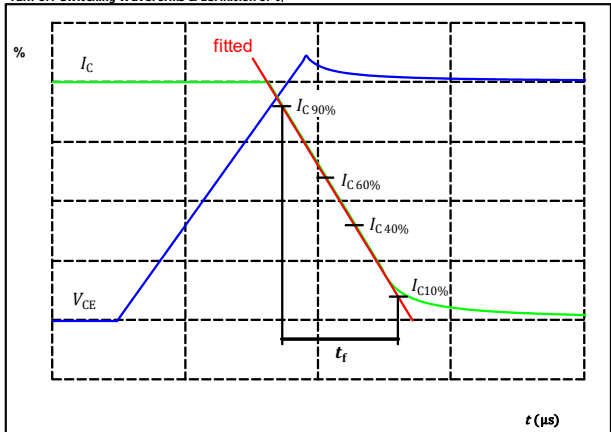
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



|                   |     |    |
|-------------------|-----|----|
| $V_{GE}(0\%) =$   | -15 | V  |
| $V_{GE}(100\%) =$ | 15  | V  |
| $V_C(100\%) =$    | 600 | V  |
| $I_C(100\%) =$    | 15  | A  |
| $t_{don} =$       | 191 | ns |

**figure 3.** IGBT

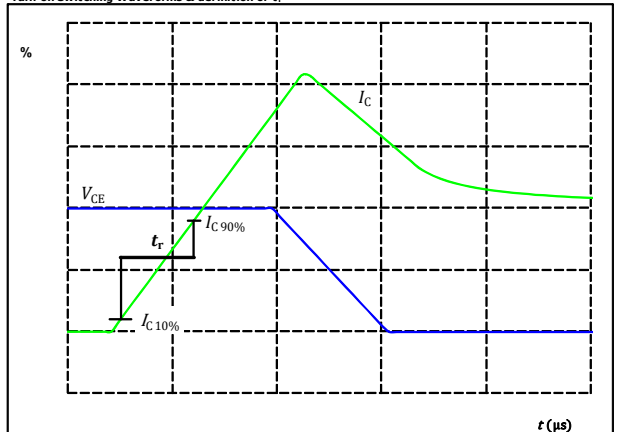
Turn-off Switching Waveforms & definition of  $t_f$



|                |     |    |
|----------------|-----|----|
| $V_C(100\%) =$ | 600 | V  |
| $I_C(100\%) =$ | 15  | A  |
| $t_f =$        | 113 | ns |

**figure 4.** IGBT

Turn-on Switching Waveforms & definition of  $t_r$



|                |     |    |
|----------------|-----|----|
| $V_C(100\%) =$ | 600 | V  |
| $I_C(100\%) =$ | 15  | A  |
| $t_r =$        | 63  | ns |

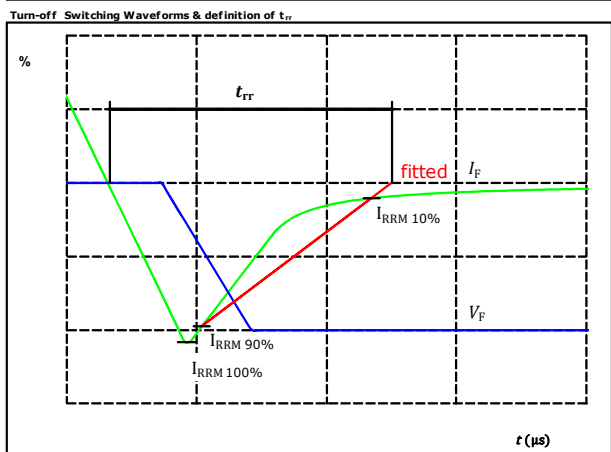


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**10-E212PMA015M7-L186A78Z**  
 datasheet

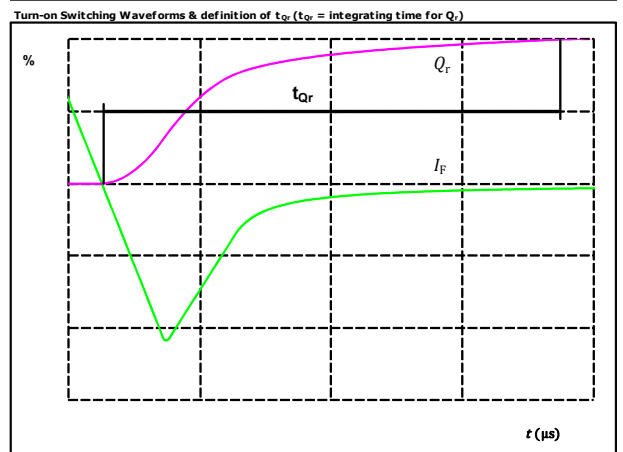
## Inverter Switching Characteristics

**figure 5.** FWD



|                    |     |    |
|--------------------|-----|----|
| $V_F(100\%) =$     | 600 | V  |
| $I_F(100\%) =$     | 15  | A  |
| $I_{RRM}(100\%) =$ | 11  | A  |
| $t_{rr} =$         | 422 | ns |

**figure 6.** FWD



|                |      |    |
|----------------|------|----|
| $I_F(100\%) =$ | 15   | A  |
| $Q_r(100\%) =$ | 2,46 | μC |



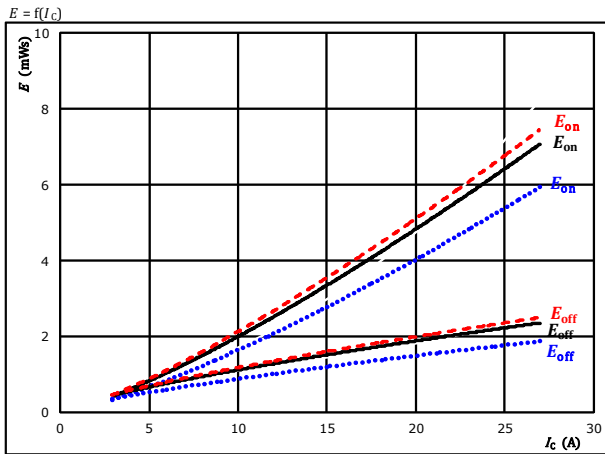
Vincotech

**10-EY12PMA015M7-L186A78T**  
**10-E212PMA015M7-L186A78Z**  
 datasheet

## Brake Switching Characteristics

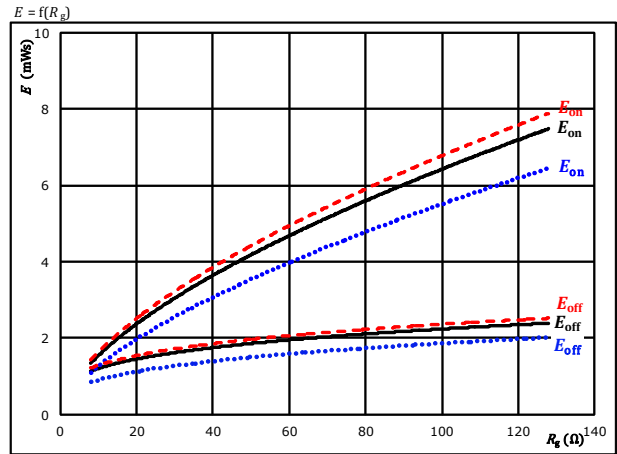
**figure 1.** IGBT

Typical switching energy losses as a function of collector current



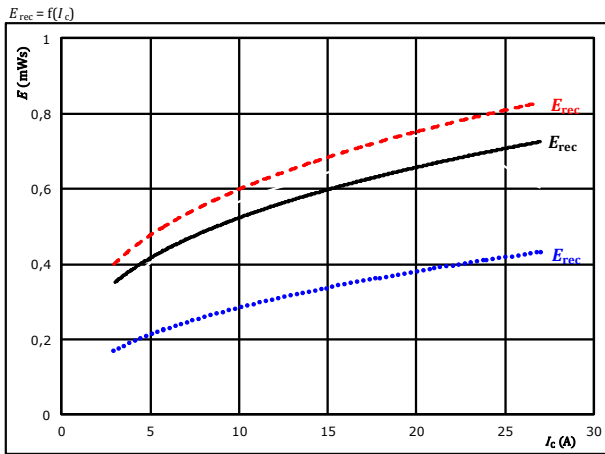
**figure 2.** IGBT

Typical switching energy losses as a function of gate resistor



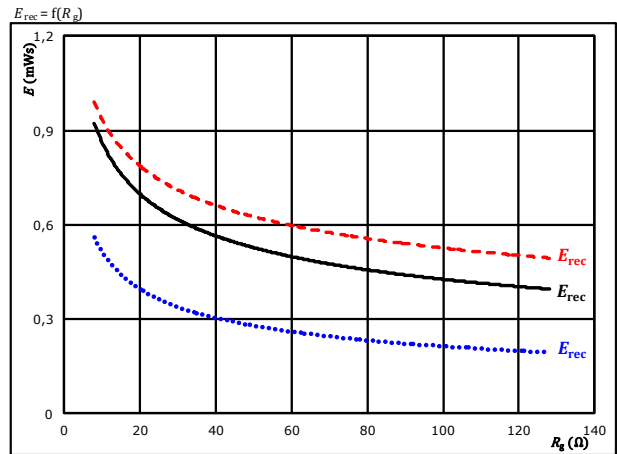
**figure 3.** FWD

Typical reverse recovered energy loss as a function of collector current



**figure 4.** FWD

Typical reverse recovered energy loss as a function of gate resistor





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## Brake Switching Characteristics

figure 5. IGBT

Typical switching times as a function of collector current

$$t = f(I_C)$$

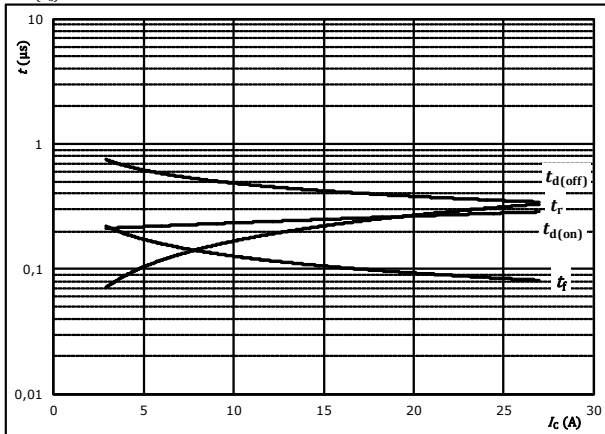


figure 6. IGBT

Typical switching times as a function of gate resistor

$$t = f(R_g)$$

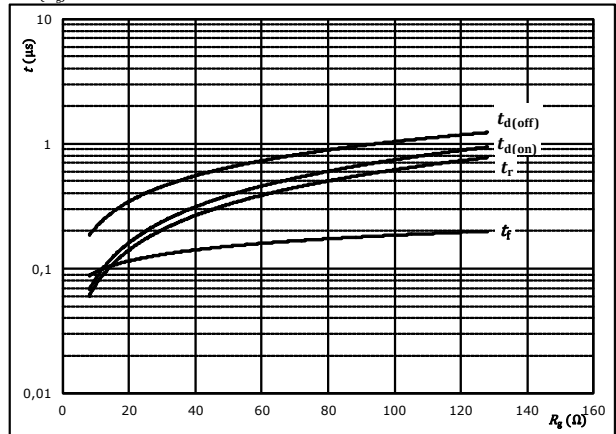


figure 7. FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_C)$$

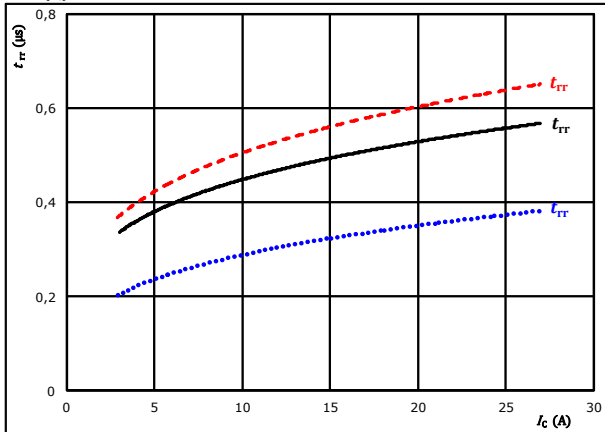
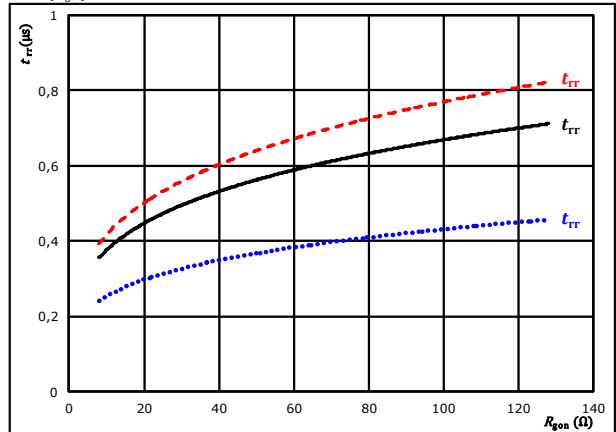


figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

$$t_{rr} = f(R_{gon})$$





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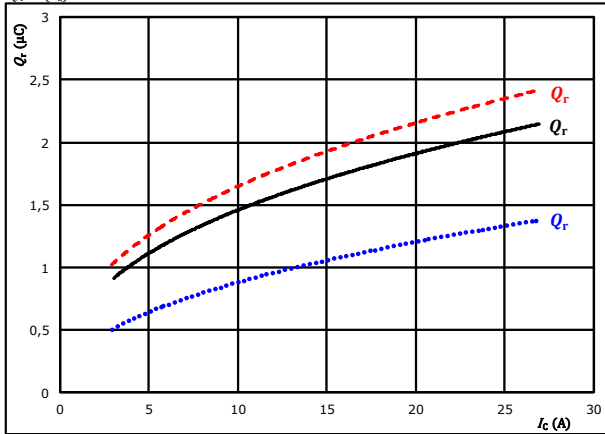
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 datasheet

## Brake Switching Characteristics

**figure 9.** FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$

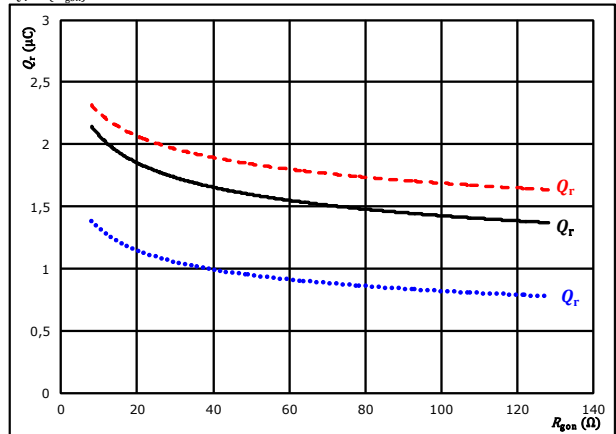


At  $V_{CE} = 600$  V  
 $V_{GE} = 0 / 15$  V  
 $R_{gon} = 32$   $\Omega$   
 $T_j$ : 25 °C (blue dotted), 125 °C (black solid), 150 °C (red dashed)

**figure 10.** FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$

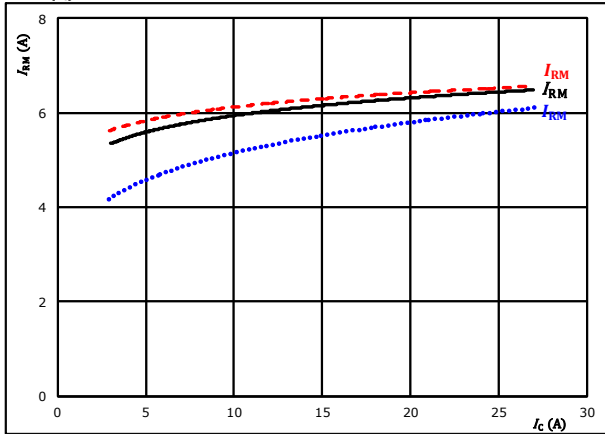


At  $V_{CE} = 600$  V  
 $V_{GE} = 0 / 15$  V  
 $I_c = 15$  A  
 $T_j$ : 25 °C (blue dotted), 125 °C (black solid), 150 °C (red dashed)

**figure 11.** FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$

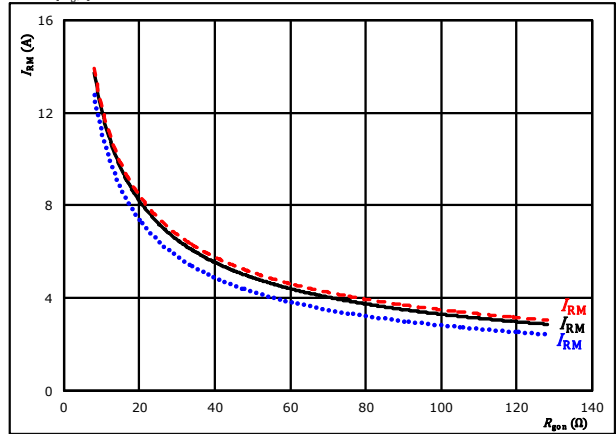


At  $V_{CE} = 600$  V  
 $V_{GE} = 0 / 15$  V  
 $R_{gon} = 32$   $\Omega$   
 $T_j$ : 25 °C (blue dotted), 125 °C (black solid), 150 °C (red dashed)

**figure 12.** FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



At  $V_{CE} = 600$  V  
 $V_{GE} = 0 / 15$  V  
 $I_c = 15$  A  
 $T_j$ : 25 °C (blue dotted), 125 °C (black solid), 150 °C (red dashed)





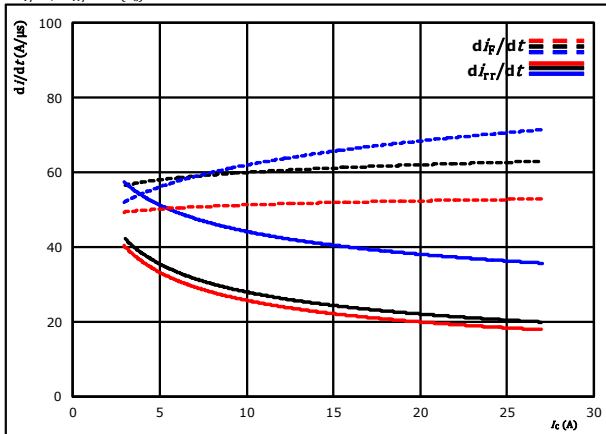
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## Brake Switching Characteristics

**figure 13.** FWD

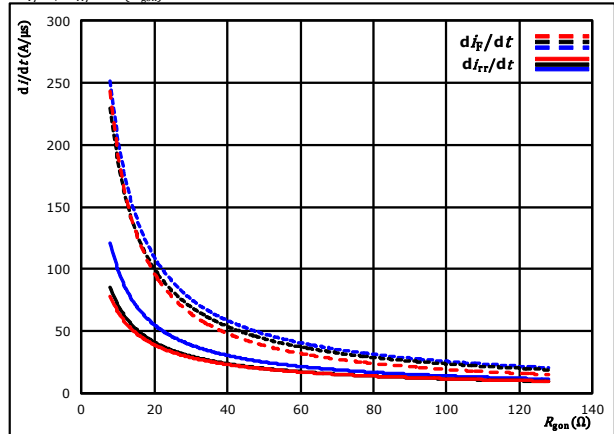
Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_{rr}/dt = f(I_C)$



At  $V_{CE} = 600$  V  
 $V_{GE} = 0 / 15$  V  
 $R_{gon} = 32$   $\Omega$   
 $T_j: 25$  °C  
 125 °C  
 150 °C

**figure 14.** FWD

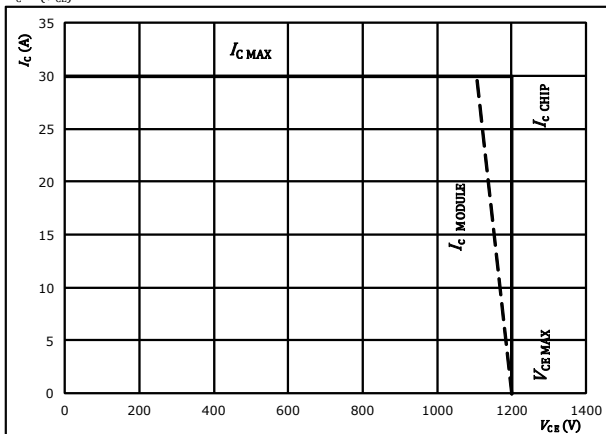
Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor  
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



At  $V_{CE} = 600$  V  
 $V_{GE} = 0 / 15$  V  
 $I_C = 15$  A  
 $T_j: 25$  °C  
 125 °C  
 150 °C

**figure 15.** IGBT

Reverse bias safe operating area  
 $I_C = f(V_{CE})$



At  $T_j = 125$  °C  
 $R_{gon} = 32$   $\Omega$   
 $R_{goff} = 32$   $\Omega$



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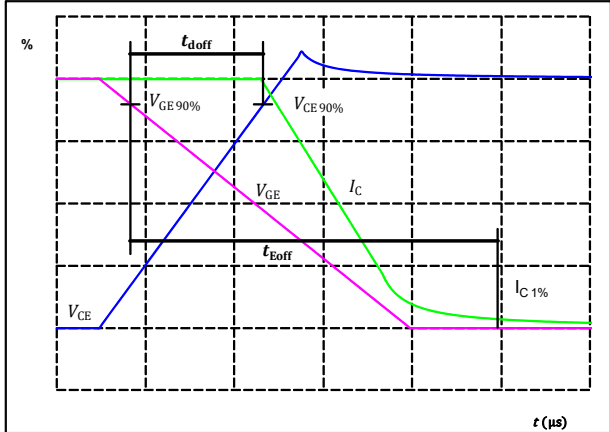
## Brake Switching Definitions

### General conditions

|            |   |             |
|------------|---|-------------|
| $T_j$      | = | 125 °C      |
| $R_{gon}$  | = | 32 $\Omega$ |
| $R_{goff}$ | = | 32 $\Omega$ |

figure 1. IGBT

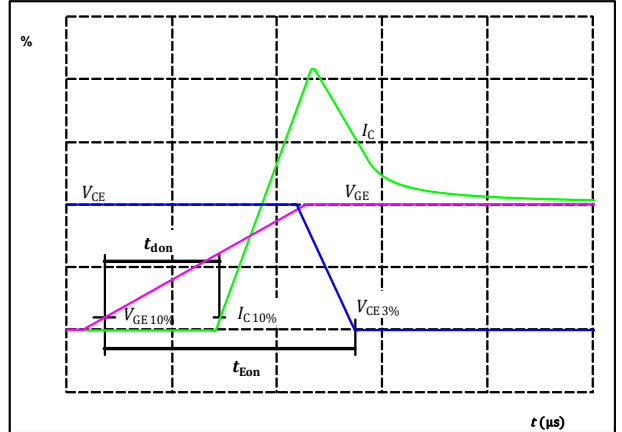
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



|                   |     |    |
|-------------------|-----|----|
| $V_{GE}(0\%) =$   | 0   | V  |
| $V_{GE}(100\%) =$ | 15  | V  |
| $V_C(100\%) =$    | 600 | V  |
| $I_C(100\%) =$    | 15  | A  |
| $t_{doff} =$      | 428 | ns |

figure 2. IGBT

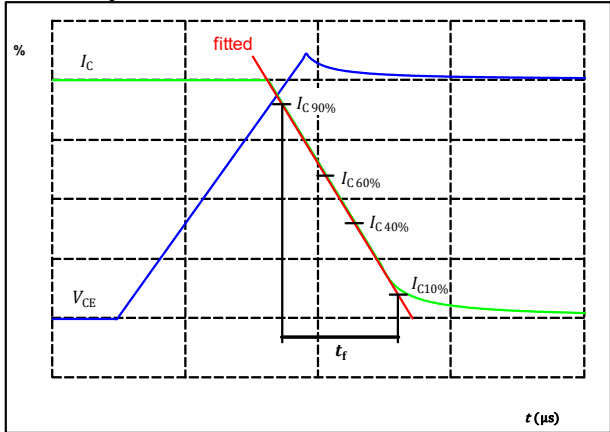
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



|                   |     |    |
|-------------------|-----|----|
| $V_{GE}(0\%) =$   | 0   | V  |
| $V_{GE}(100\%) =$ | 15  | V  |
| $V_C(100\%) =$    | 600 | V  |
| $I_C(100\%) =$    | 15  | A  |
| $t_{don} =$       | 262 | ns |

figure 3. IGBT

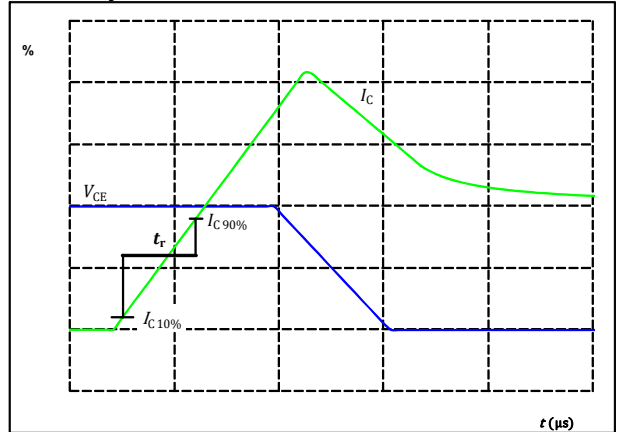
Turn-off Switching Waveforms & definition of  $t_f$



|                |     |    |
|----------------|-----|----|
| $V_C(100\%) =$ | 600 | V  |
| $I_C(100\%) =$ | 15  | A  |
| $t_f =$        | 87  | ns |

figure 4. IGBT

Turn-on Switching Waveforms & definition of  $t_r$



|                |     |    |
|----------------|-----|----|
| $V_C(100\%) =$ | 600 | V  |
| $I_C(100\%) =$ | 15  | A  |
| $t_r =$        | 205 | ns |



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## Brake Switching Characteristics

figure 5. FWD

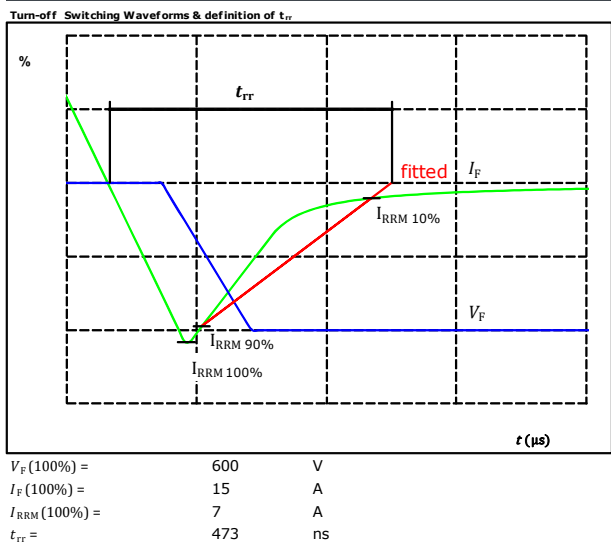
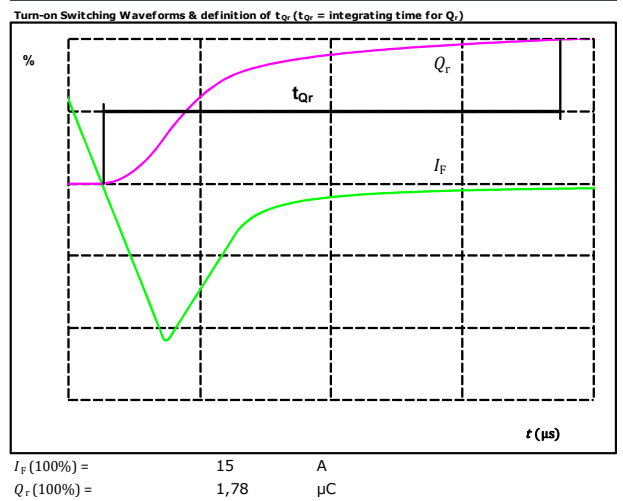


figure 6. FWD





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datasheet

| Ordering Code & Marking                                                                                                                                                                                                                                     |  |  |                              |          |                            |           |           |       |        |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|------------------------------|----------|----------------------------|-----------|-----------|-------|--------|
| Version                                                                                                                                                                                                                                                     |  |  | Ordering Code                |          |                            |           |           |       |        |
| without thermal paste 12 mm housing with press-fit pins                                                                                                                                                                                                     |  |  | 10-EY12PMA015M7-L186A78T     |          |                            |           |           |       |        |
| with thermal paste 12 mm housing with press-fit pins                                                                                                                                                                                                        |  |  | 10-EY12PMA015M7-L186A78T-/3/ |          |                            |           |           |       |        |
| without thermal paste 12 mm housing with Solder pins                                                                                                                                                                                                        |  |  | 10-E212PMA015M7-L186A78Z     |          |                            |           |           |       |        |
| with thermal paste 12 mm housing with Solder pins                                                                                                                                                                                                           |  |  | 10-E212PMA015M7-L186A78Z-/3/ |          |                            |           |           |       |        |
| <div><div>NN-NNNNNNNNNNNNNN<br/>TTTTTUVVWWYY UL<br/>VIN LLLLL SSSS</div><div></div></div> |  |  | Text                         |          | Name                       | Date code | UL & VIN  | Lot   | Serial |
|                                                                                                                                                                                                                                                             |  |  |                              |          | NN-NNNNNNNNNNNNNN-TTTTTTVV | WWYY      | UL VIN    | LLLLL | SSSS   |
|                                                                                                                                                                                                                                                             |  |  | Datamatrix                   | Type&Ver | Lot number                 | Serial    | Date code |       |        |
|                                                                                                                                                                                                                                                             |  |  |                              | TTTTTUVV | LLLLL                      | SSSS      | WWYY      |       |        |

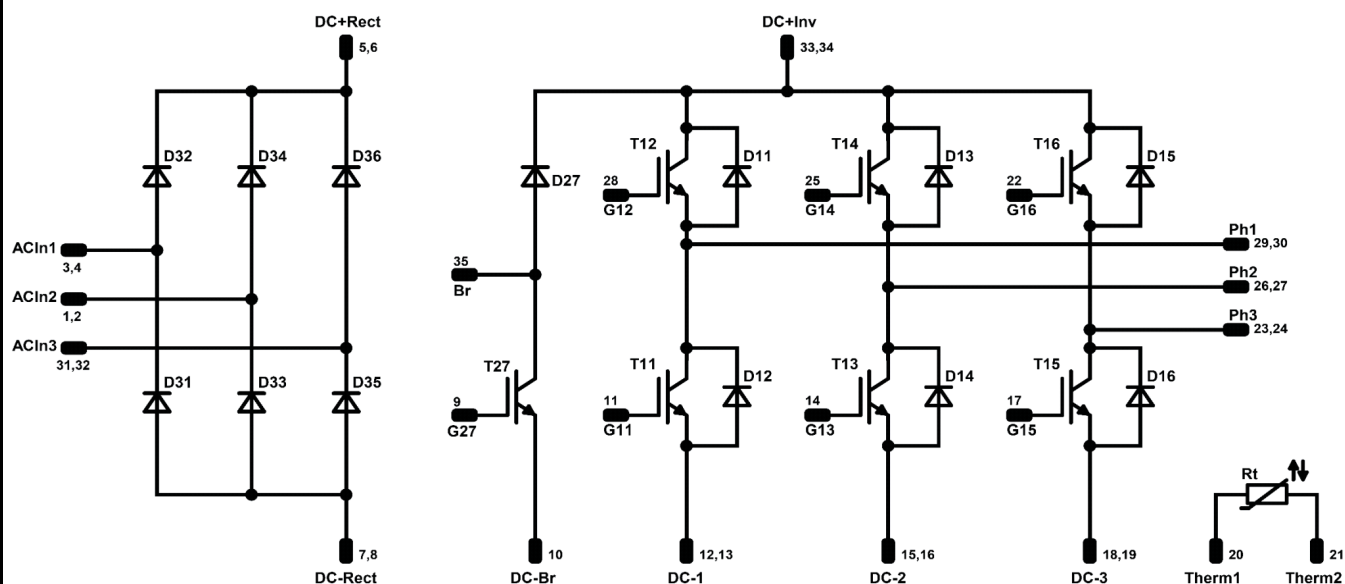
| Pin table |      |      |          | Outline       |  |
|-----------|------|------|----------|---------------|--|
| Pin       | X    | Y    | Function |               |  |
| 1         | 25,6 | 6,4  | ACIn2    | Solder pin    |  |
| 2         | 22,4 | 6,4  | ACIn2    |               |  |
| 3         | 16   | 9,6  | ACIn1    | Press-fit pin |  |
| 4         | 12,8 | 9,6  | ACIn1    |               |  |
| 5         | 9,6  | 0    | DC+Rect  |               |  |
| 6         | 9,6  | 3,2  | DC+Rect  |               |  |
| 7         | 0    | 0    | DC-Rect  |               |  |
| 8         | 0    | 3,2  | DC-Rect  |               |  |
| 9         | 0    | 16   | G27      |               |  |
| 10        | 0    | 19,2 | DC-Br    |               |  |
| 11        | 0    | 22,4 | G11      |               |  |
| 12        | 0    | 25,6 | DC-1     |               |  |
| 13        | 0    | 28,8 | DC-1     |               |  |
| 14        | 0    | 32   | G13      |               |  |
| 15        | 0    | 35,2 | DC-2     |               |  |
| 16        | 0    | 38,4 | DC-2     |               |  |
| 17        | 0    | 41,6 | G15      |               |  |
| 18        | 0    | 44,8 | DC-3     |               |  |
| 19        | 0    | 48   | DC-3     |               |  |
| 20        | 9,6  | 48   | Therm1   |               |  |
| 21        | 19,2 | 48   | Therm2   |               |  |
| 22        | 28,8 | 48   | G16      |               |  |
| 23        | 32   | 48   | Ph3      |               |  |
| 24        | 32   | 44,8 | Ph3      |               |  |
| 25        | 32   | 35,2 | G14      |               |  |
| 26        | 32   | 32   | Ph2      |               |  |
| 27        | 32   | 28,8 | Ph2      |               |  |
| 28        | 32   | 19,2 | G12      |               |  |
| 29        | 32   | 16   | Ph1      |               |  |
| 30        | 32   | 12,8 | Ph1      |               |  |
| 31        | 32   | 3,2  | ACIn3    |               |  |
| 32        | 32   | 0    | ACIn3    |               |  |
| 33        | 22,4 | 19,2 | DC+Inv   |               |  |
| 34        | 22,4 | 16   | DC+Inv   |               |  |
| 35        | 9,6  | 19,2 | Br       |               |  |
|           |      |      |          |               |  |



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**Pinout**



**Identification**

| ID                           | Component | Voltage | Current | Function        | Comment |
|------------------------------|-----------|---------|---------|-----------------|---------|
| T11, T12, T13, T14, T15, T16 | IGBT      | 1200 V  | 15 A    | Inverter Switch |         |
| D11, D12, D13, D14, D15, D16 | FWD       | 1200 V  | 15 A    | Inverter Diode  |         |
| T27                          | IGBT      | 1200 V  | 15 A    | Brake Switch    |         |
| D27                          | FWD       | 1200 V  | 10 A    | Brake Diode     |         |
| D31, D32, D33, D34, D35, D36 | Rectifier | 1600 V  | 35 A    | Rectifier Diode |         |
| Rt                           | NTC       |         |         | Thermistor      |         |



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| Packaging instruction                 |      |          |             |
|---------------------------------------|------|----------|-------------|
| Standard packaging quantity (SPQ) 100 | >SPQ | Standard | <SPQ Sample |

| Handling instruction                                                         |
|------------------------------------------------------------------------------|
| Handling instructions for <i>flow</i> E2 packages see vincotech.com website. |

| Package data                                                        |
|---------------------------------------------------------------------|
| Package data for <i>flow</i> E2 packages see vincotech.com website. |

| UL recognition and file number                                                                                                                                                                                      |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.  |

| Document No.:                  | Date:        | Modification:                            | Pages |
|--------------------------------|--------------|------------------------------------------|-------|
| 10-Ex12PMA015M7-L186A78x-D4-14 | 09 Dec. 2020 | Add note to Operation temperature rating | 3     |

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